	Reg. I	No.:							
		Question P	Paper Co	de:R2P()5				
	B.E./B.Te	ech. DEGREE EXA	MINATIO	N, APRIL	/ MAY	2025			
			nd Semester						
		Electrical and El	lectronics E	ngineering	5				
	R21UPH20	05 - PHYSICS FOR				RING	r		
		(Regula	ntions R202	1)					
		(Common to ECE	E Engineerin	ng branche	es)				
Dur	ation: Three hours				M	aximu	ım: 10	00 Ma	ırks
		PART A - (1	$0 \times 1 = 10$	Marks)					
1.)1 - U		
	(a) Silicon	(b) Germanium	(c) G	old		(d) Ga	ıllium	Arse	nide
2.	2. When the high resistivity material (Nichrome) is connected in AC current						CC)1- U	
	(a) Heat produced	(b) Cool	(c) N	o effect		(d) Me	elt the	wire	
3.	The probability of occupancy of Fermi level at any temperature other than 0 K is							CC) 1- U
	(a) Zero	(b) one	(c) in	nfinity		(d) 0.5	5		
4. The compound semiconductor have and carrier mobility								CC)1- U
	(a) Low forbidden gap		(b) Le	(b) Less forbidden gap					
	(c) Large forbidden gap		(d) No	(d) None of these					
5.	Which of the following is a weak magnet?							CC)2- U
	(a) Ferromagnetic material		(b) Ar	(b) Antiferromagnetic					
	(c) Ferromagnetic material		(d) Ar	(d) Antiferromagnetic					
6.	The magnetic permea	bility of a paramag	netic substa	ince is				CC)2- U

(c) 1

(d) None of these

(b) <1

(a) > 1

7.	How does ionic polarization occur?					
	(a) S	Splitting of ions	(b) Passing magnetic field			
	(c) l	Displacement of cations and anions	(d) Never occurs			
8.	The	fastest polarization is	C	O2- U		
	(a) i	ionic polarization	(b) space-charge polariza	tion		
	(c) (Oriental polarization	n			
9.	Which one of the following nano materials comes under two dimensional?				O2- U	
	(a) l	Nanoparticles	(b) Nanorods			
	(c) l	Nanofilms				
10.	The	C	O5-Ap			
	(a)	40 micron	(b) 4.6 micron			
	(c)	200-300 micron	(d) None of the above			
		PART - B (5 x	2= 10 Marks)			
11.	Def	ine Fermi level and Fermi energy in meta	als with its importance.	CO1	- U	
12.	Wha	CO1	CO1- U			
13.	Def	CO2	CO2- U			
14.	Wha	CO2	CO2- U			
15.	What are the optical materials?				CO2- U	
		PART – C (5	x 16= 80Marks)			
16.	(a) Derive the expression for electrical conductivity and thermal Conductivity in metals. Derive Lorentz number. Or			CO3-App	(16)	
	(b)	Obtain the Fermi Dirac distribution to function varies with temperature?	function. Explain how the	CO3-App	(16)	
17.	(a)	Derive an expression for the electrical semiconductors. How will you determine intrinsic semiconductor?	•	CO3-App	(16)	

- (b) What is Hall effect? Show that for a p type semiconductor the CO3-App Hall coefficient $R_{\rm H}$ is given by 1/pe.
- 18. (a) Describe the ferromagnetic domain theory in detail and how will CO2- U you account hysteresis of ferromagnetic material based on domain theory. (16)

Or

- (b) Explain dia, para and ferro magnetic materials on the basis of CO2-U spin. Distinguish between soft and hard magnetic materials.
- 19. (a) Derive an expression for Langevin-Debye equation. CO5- App (16)
 Or
 - (b) Arrive at the expression for dielectric power loss and explain how CO5- App it varies with frequency of the applied voltage.
- 20. (a) Compare the quantum confinement and resulting structures like CO2-U (16) Quantum dots, quantum wells and their physical significance.

Or

(b) Describe single electron phenomena and single electron CO2-U (16) transistor.